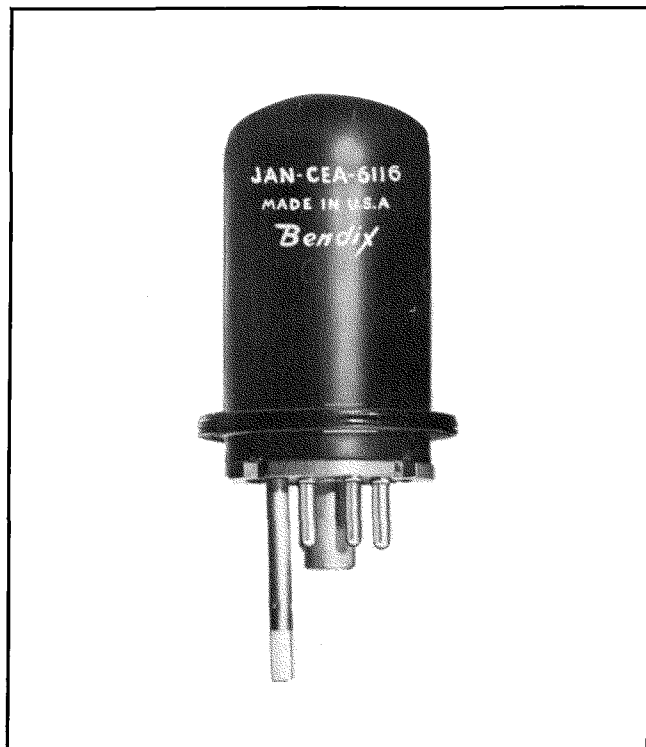


REFLEX KLYSTRON

(THERMALLY TUNED)



MAXIMUM RATINGS

(ABSOLUTE VALUES)

Resonator Voltage	350 volts D.C.
Reflector Voltage	—350 volts D.C.
Filament Voltage	$6.3 \pm 8\%$ volts
Gun Cathode Current.....	32 ma. D.C.
Diode Plate Dissipation.....	*see note below
Diode Voltage	—350 volts D.C.
Heater-Cathode Voltage.....	± 100 volts D.C.

*Note: Power inputs as high as 16.5 watts may be applied to the diode when the frequency of the klystron is above 8500. Tuner power in excess of 10 watts may permanently damage the tuning structure, if applied when the tube is tuned below 8500 Mc.

DESCRIPTION

The 6116 (Bendix® Type TK-62) tube is a ruggedized low voltage thermally tuned X-band reflex klystron, designed for use as a CW power source over the frequency range of 8500 to 9660 Mc./sec. Thermal tuning of the klystron is accomplished by means of a diode included within the vacuum envelope, the plate of which comprises one wall of the klystron cavity. As diode voltage, and hence current, is increased, expansion of the plate results in corresponding changes in the klystron cavity gap spacing causing the tube to tune. The tuning speed over the required frequency range is .7 to 3 seconds.

With the exception of the diode tuner, the 6116 may be considered a ruggedized version of the 2K45 with equivalent outline dimensions and electrical characteristics.

The ruggedization feature of the tube permits it to be operated under severe vibration environments without sacrifice of frequency stability. Under vibration conditions of 10g acceleration at 50 cycles, the maximum frequency variation is ± 1.3 Mc./sec.

The tube has coaxial output as shown in the accompanying photograph and outline drawing, and is coupled to the waveguide circuit through a transducer identical to that used for the type 2K45 and 2K25 klystrons. Details of this transducer can be found in the Military Number 227 JAN specification sheet.

TYPICAL OPERATING CONDITIONS

Frequency	8500 to 9660 Mc./sec.
Resonator Voltage.....	300 volts D.C.
Reflector Voltage	
@ 9660 Mc./sec.....	—95 to —145 volts D.C.
Filament Voltage.....	$6.3 \pm 8\%$ volts
Gun Cathode Current.....	32 mA D.C. (max.)
Tuner Diode Current.....	5 to 36 ma (D.C.)
Tuner Diode Voltage.....	170 to 275 volts D.C.

PHYSICAL CHARACTERISTICS

- Base: Small octal 8-pin, B8-21, Low Loss Phenolic Wafer, Modified for coaxial output lead as shown on outline drawing.
- Coupling to Wave Guide: Coaxial output fits standard transducer per 227 JAN.
- Cooling: Convection.
- Mounting Position: Any.
- Cavity: Integral with tube.
- Bulb: Metal.

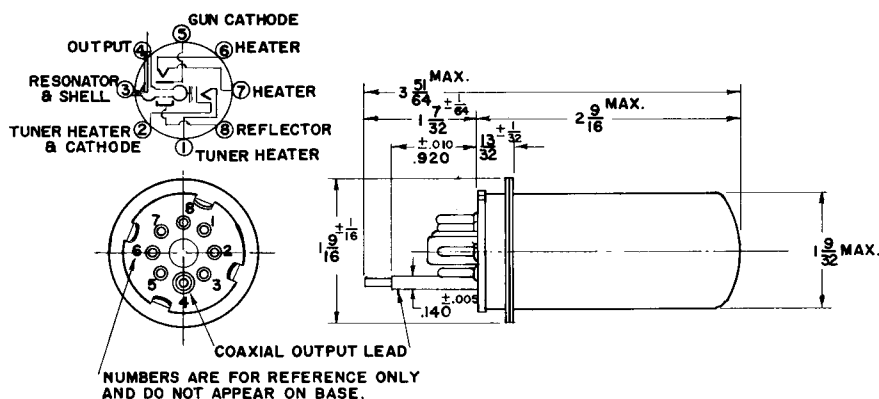
THE **Bendix** CORPORATION

Red Bank DIVISION, EATONTOWN, NEW JERSEY

ELECTRICAL CHARACTERISTICS & TEST CONDITIONS

Test Conditions and Specification Limits

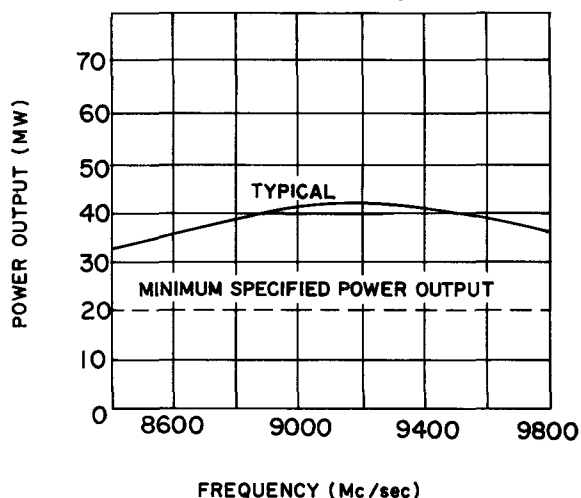
TEST	CONDITIONS	SYMBOL	LIMITS		UNITS
			MIN.	MAX.	
PRODUCTION TESTS:					
Total Reflector Current:	Er = -150 Vdc; t = 120 sec.(min)	Ir:	—	5.0	μAdc
Reflector Leakage:	Er = -150 Vdc	Ir:	—	3.0	μAdc
Reflector Gas Current:	Er = -150 Vdc	Ir:	—	1.0	μAdc
Cathode Current (1):	Er = -150 Vdc	Ik1:	—	32	mAdc
Reflector Voltage:	Er (Mode A)/Max. Po @ 9660 ±0.3 % Mc.	Er:	-95	-145	Vdc
Emission (1):	Ef = 5.8; Er = -150 Vdc	ΔIk1/Ik1:	—	0.15	
Emission (2):	Ef = 5.8; Ik2 = 20 mA	ΔIk2/Ik2:	—	0.10	
Thermal Tuning Time (1):	F = 9660 to 8500 Mc.	t:	0.7	3.0	sec.
Thermal Tuning Time (2):	F = 8500 to 9660 Mc.	t:	0.7	3.0	sec.
Power Output:	Ef = 5.8; F from 8500 to 9660 Mc.	Po:	20	—	mW
DESIGN TESTS:					
Electrode Insulation:	300 Vdc Tube Cold	Rk1-rs:	2.0	—	Meg.
		Rk2-rs:	2.0	—	Meg.
		RF1-rs:	2.0	—	Meg.
Heater Current (1):		If1:	465	570	mA
Heater Current (2):		If2:	720	880	mA
Insulation:	Eh-K1 = ±100 Vdc	IhK1:	—	100	μAdc
Bump:	Ef = 5.8; Er (Mode A)/Max. Po @ 9660 ±0.3 % Mc.	ΔPo/Po:	—	0.10	
Thermal Tuning Range:	Ef = 5.8 V; Er (Mode A)/Max. Po Pp = 1.0 to 9.0 watts	Max. F:	9660	—	Mc
		Min. F:	—	8500	Mc
Tuner Diode Voltage Drop (1):	Ik2 = 10 mAdc	ED:	170	218	Vdc
Tuner Diode Voltage Drop (2):	Ik2 = 28 mAdc	ED:	225	274	Vdc
Tuner Diode Voltage (1):	F = 9660 ±0.03 % Mc. Er (Mode A)/Max. Po	ED:	170	230	Vdc
Tuner Diode Voltage (2):	F = 9080 ±0.3 % Mc. Er (Mode A)/Max. Po	ED:	200	260	Vdc
Tuner Diode Voltage (3):	F = 8500 ±0.3 % Mc. Er (Mode A)/Max. Po	ED:	220	275	Vdc
Tuner Diode Current (1):	F = 9660 ±0.03 % Mc. Er (Mode A)/Max. Po	Ik2:	5	19	mA
Tuner Diode Current (2):	F = 9080 ±0.3 % Mc. Er (Mode A)/Max. Po	Ik2:	13	28	mA
Tuner Diode Current (3):	F = 8500 ±0.3 % Mc. Er (Mode A)/Max. Po	Ik2:	20	36	mA
Electrical Tuning Range:	Er (Mode A)/50 % Max. Po: F from 8500 to 9660 Mc.	F:	45	—	Mc
Vibration:	Er (Mode A)/Max. Po at 9080 Mc; Total Displacement = 0.080" F = 50 cps, Position X1 and Y1	ΔF:	—	±1300	Kc



OUTLINE DRAWING

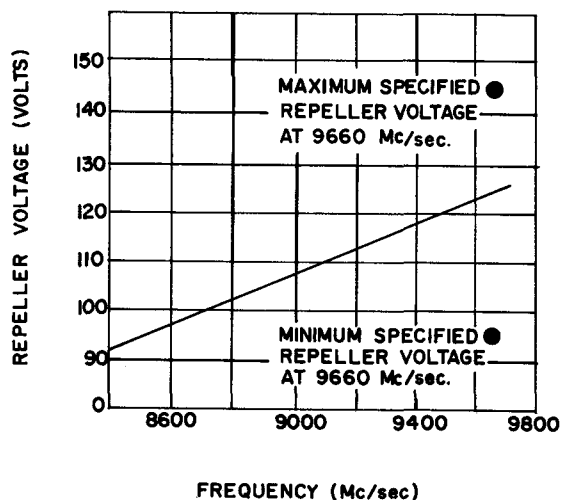
AVERAGE CHARACTERISTICS

**TYPICAL POWER OUTPUT
V S
FREQUENCY**
REPELLER VOLTAGE
OPTIMIZED FOR EACH FREQUENCY



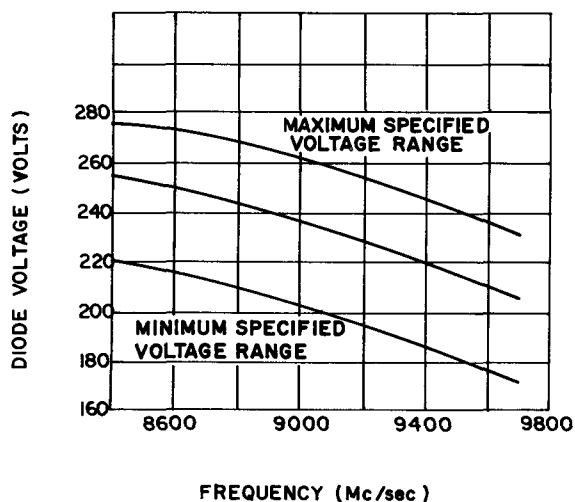
POWER OUTPUT VS FREQUENCY
(REPELLER VOLTAGE OPTIMIZED FOR EACH FREQUENCY)

**TYPICAL VARIATION
OF REPELLER VOLTAGE
V S
FREQUENCY**



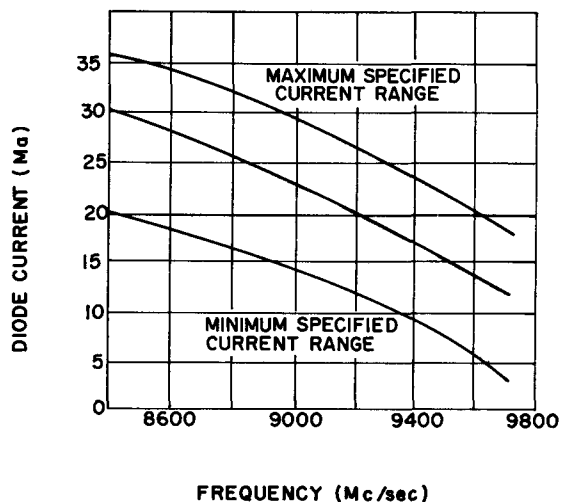
REPELLER VOLTAGE VS FREQUENCY

**TYPICAL TUNER DIODE
VOLTAGE
V S
FREQUENCY**



TUNER DIODE VOLTAGE VS FREQUENCY

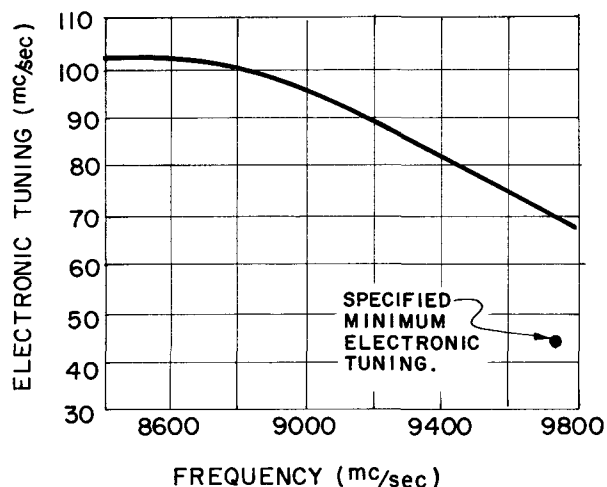
**TYPICAL TUNER DIODE
CURRENT
V S
FREQUENCY**



TUNER DIODE CURRENT VS FREQUENCY

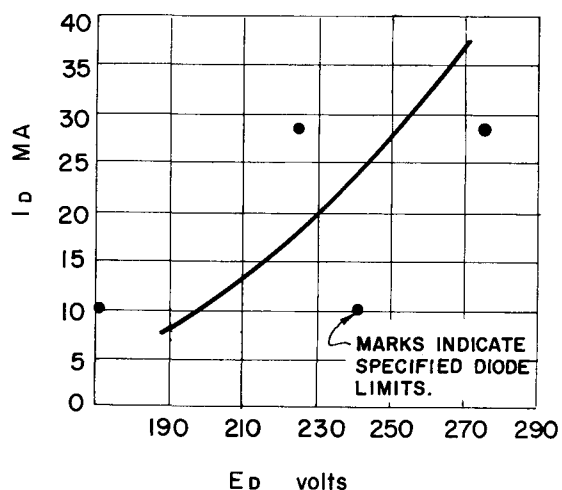
AVERAGE CHARACTERISTICS

TYPICAL VARIATION OF
HALF POWER ELECTRONIC
TUNING RANGE
VS
FREQUENCY

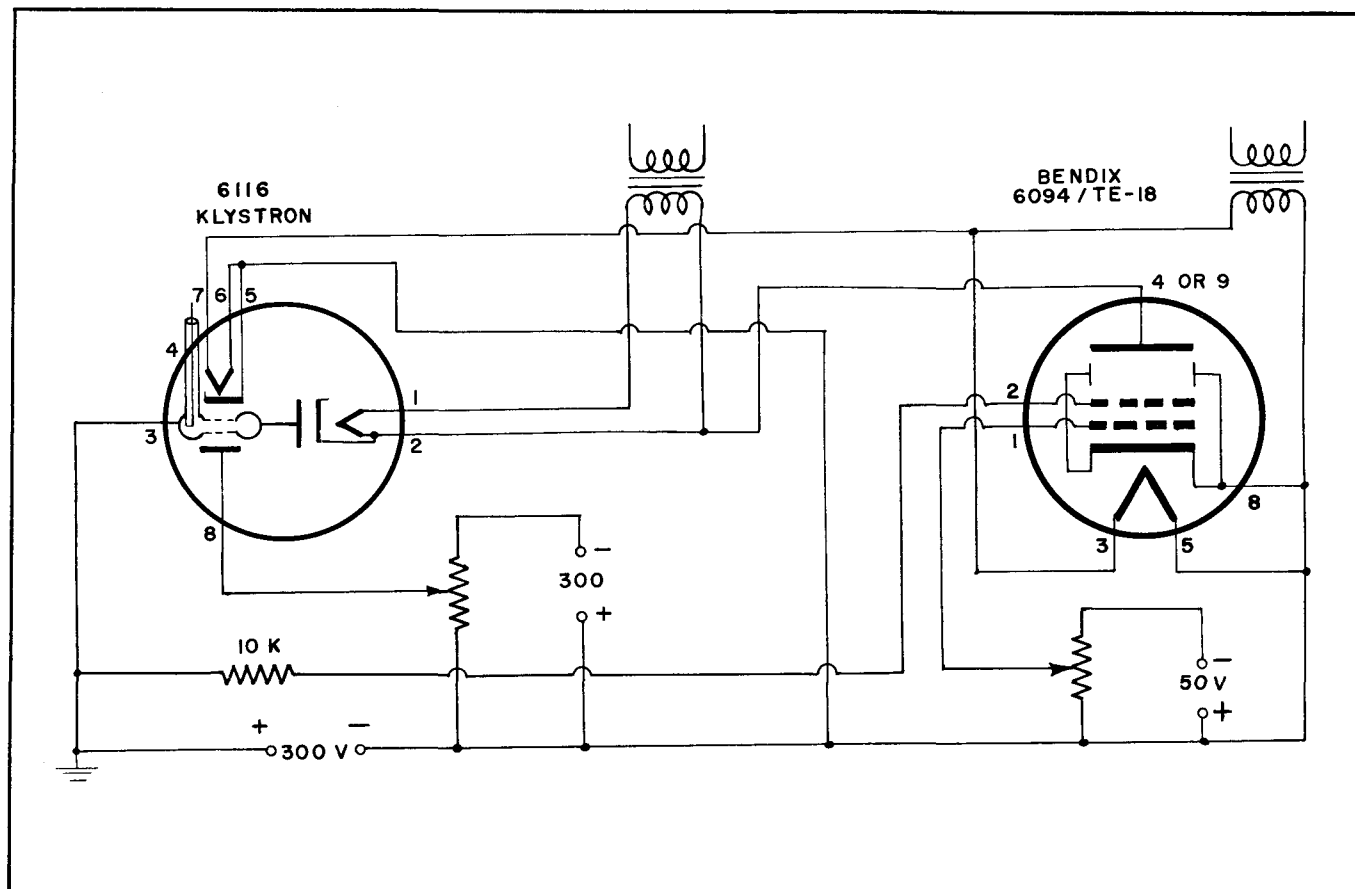


HALF POWER ELECTRONIC TUNING
RANGE VS FREQUENCY

TYPICAL STATIC DIODE
CHARACTERISTICS



STATIC DIODE CHARACTERISTICS



CONTROL CIRCUIT FOR TUNING DIODE